

NXPS20H110C Dual power Schottky diode Rev. 2 — 24 May 2012

Product data sheet

#### **Product profile** 1.

### 1.1 General description

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a SOT78 (TO-220AB) plastic package.

### **1.2 Features and benefits**

- High junction temperature capability
- Low leakage current

#### Negligible switching losses

Optimised design to give low V<sub>F</sub> and high T<sub>i(max)</sub>

### **1.3 Applications**

- DC to DC converters
- Freewheeling diode

- OR-ing diode
- Switched mode power supply rectifier

### 1.4 Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	110	V
I <sub>F(AV)</sub>	average forward current	square-wave pulse; $\delta = 0.5$ ; T <sub>j</sub> ≤ 163 °C; per diode; see <u>Figure 1</u> ; see <u>Figure 2</u> ; see <u>Figure 3</u>	-	-	10	A
I <sub>O(AV)</sub>	average output current	square-wave pulse; $\delta = 0.5$ ; T <sub>mb</sub> ≤ 161 °C; both diodes conducting	-	-	20	А
Tj	junction temperature		-	-	175	°C
Static cha	racteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 A; T <sub>j</sub> = 25 °C; see <u>Figure 6</u>	-	-	0.77	V
		$I_F = 10 \text{ A}; T_j = 125 \text{ °C}; \text{ see } \frac{\text{Figure 6}}{1000 \text{ G}}$	-	0.59	0.64	V
I <sub>R</sub>	reverse current	$V_R$ = 110 V; $T_j$ = 25 °C; see <u>Figure 7</u>	-	2.5	6	μA
		$V_R$ = 110 V; $T_j$ = 125 °C; see <u>Figure 7</u>	-	1.5	6.5	mA



## 2. Pinning information

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		
2	К	cathode	mb	
3	A2	anode 2		К
mb	к	mounting base; cathode		sym125

SOT78 (TO-220AB)

## 3. Ordering information

Table 3.         Ordering information						
Type number	Package					
	Name	Description	Version			
NXPS20H110C	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			

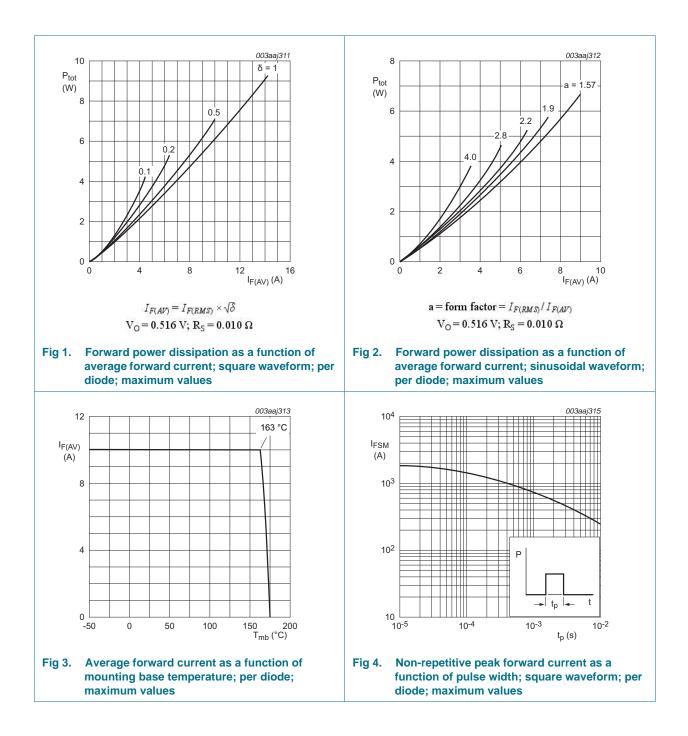
## 4. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	110	V
I <sub>F(AV)</sub>	average forward current	square-wave pulse; $\delta = 0.5$ ; $T_j \le 163$ °C; per diode; see <u>Figure 1</u> ; see <u>Figure 2</u> ; see <u>Figure 3</u>	-	10	A
I <sub>O(AV)</sub>	average output current	square-wave pulse; $\delta = 0.5$ ; $T_{mb} \le 161 \text{ °C}$ ; both diodes conducting	-	20	A
I <sub>FSM</sub>	non-repetitive peak forward current	sine-wave pulse; $t_p = 10 \text{ ms}$ ; $T_{j(init)} = 25 \text{ °C}$ ; see Figure 4	-	250	A
T <sub>stg</sub>	storage temperature		-65	175	°C
Ti	junction temperature		-	175	°C

**Dual power Schottky diode** 

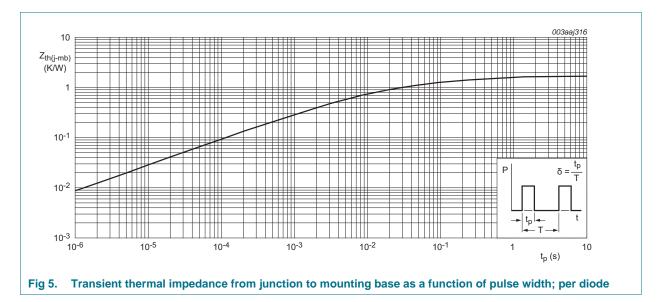


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## 5. Thermal characteristics

Table 5.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	with heatsink compound; per diode; see Figure 5	-	-	1.6	K/W
		with heatsink compound; both diodes conducting	-	-	0.9	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	60	-	K/W

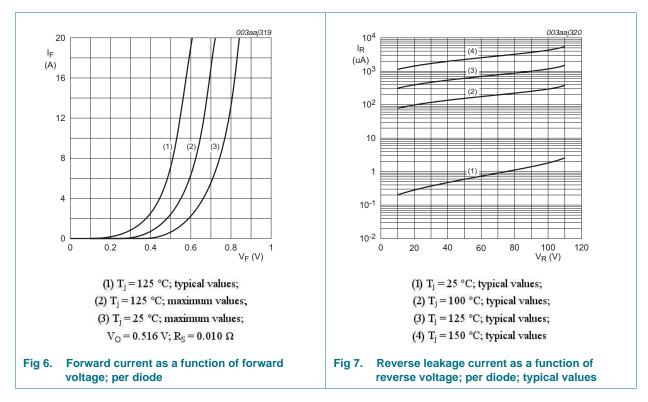


**Dual power Schottky diode** 

## 6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static cha	aracteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 25 °C; see <u>Figure 6</u>	-	-	0.71	V
		I <sub>F</sub> = 10 A; T <sub>j</sub> = 25 °C; see <u>Figure 6</u>	-	-	0.77	V
		I <sub>F</sub> = 16 A; T <sub>j</sub> = 25 °C; see <u>Figure 6</u>	-	-	0.81	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C; see <u>Figure 6</u>	-	-	0.88	V
		I <sub>F</sub> = 8 A; T <sub>j</sub> = 125 °C; see <u>Figure 6</u>	-	0.56	0.58	V
		I <sub>F</sub> = 10 A; T <sub>j</sub> = 125 °C; see <u>Figure 6</u>	-	0.59	0.64	V
		I <sub>F</sub> = 16 A; T <sub>j</sub> = 125 °C; see <u>Figure 6</u>	-	0.65	0.68	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 125 °C; see <u>Figure 6</u>	-	0.67	0.73	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 110 V; T <sub>j</sub> = 25 °C; see <u>Figure 7</u>	-	2.5	6	μA
		V <sub>R</sub> = 110 V; T <sub>j</sub> = 125 °C; see <u>Figure 7</u>	-	1.5	6.5	mA
Dynamic	characteristics					
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 10 V; T <sub>i</sub> = 25 °C;	-	250	-	pF

f = 1 MHz; V<sub>R</sub> = 10 V; T<sub>j</sub> = 25 °C; see <u>Figure 8</u>

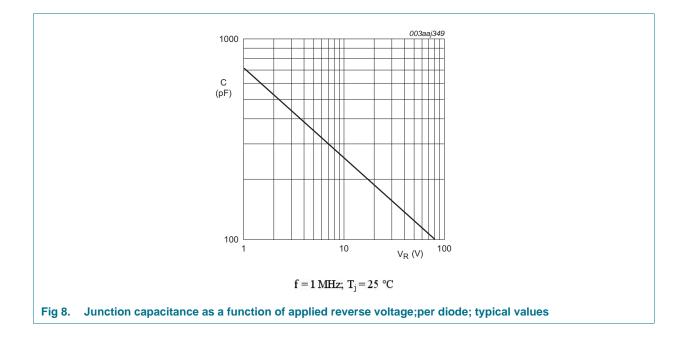


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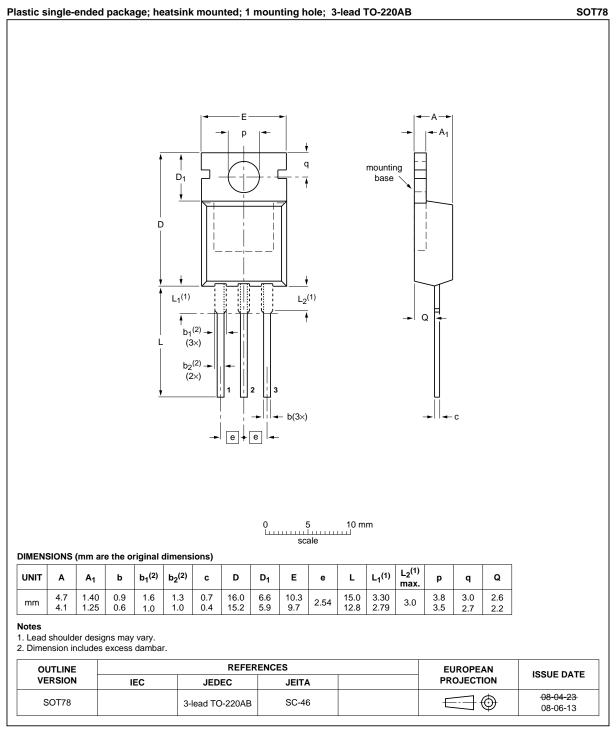
#### **Dual power Schottky diode**





**Dual power Schottky diode** 

## 7. Package outline



#### Fig 9. Package outline SOT78 (TO-220AB)

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## 8. Revision history

Table 7. Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NXPS20H110C v.2	20120524	Product data sheet	-	NXPS20H110C v.1
Modifications:	<ul> <li>Status change</li> </ul>	ed from preliminary to produc	t.	
	<ul> <li>Various chang</li> </ul>	ges to content.		
NXPS20H110C v.1	20120420	Preliminary data shee	t -	-

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#### 9.1 Data sheet status

Document status <sup>[1]</sup> [2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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